

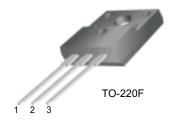
## FFPF06U20DP

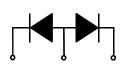
### **Features**

- · Ultrafast with soft recovery.
- · Low forward voltage.

## **Applications**

- Power switching circuits.
- · Output rectifiers.
- Freewheeling diodes.
- Switching mode power supply.





1. Cathode 2. Anode 3. Cathode

## **FAST RECOVERY POWER RECTIFIER**

### Absolute Maximum Ratings (per diode) T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	200	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 100°C	6	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	Α
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and Storage Temperature	- 65 to +150	°C

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
R <sub>e.IC</sub>	Maximum Thermal Resistance, Junction to Case	8.0	°C/W

### Electrical Characteristics (per diode) T<sub>C</sub>=25 °C unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V <sub>FM</sub> *	Maximum Instantaneous Forward Voltage					V
	I <sub>F</sub> = 6A	T <sub>C</sub> = 25 °C	-	-	1.2	
	I <sub>F</sub> = 6A	T <sub>C</sub> = 25 °C T <sub>C</sub> = 100 °C	-	-	1.0	
I <sub>RM</sub> *	Maximum Instantaneous Reverse Current					μΑ
	@ rated V <sub>R</sub>	T <sub>C</sub> = 25 °C	-	-	6	
		$T_C = 25  ^{\circ}C$ $T_C = 100  ^{\circ}C$	-	-	60	
t <sub>rr</sub>	Maximum Reverse Recovery Time		-	-	35	ns
I <sub>rr</sub>	Maximum Reverse Recovery Current		-	-	2.5	Α
Q <sub>rr</sub>	Maximum Reverse Recovery Charge (I <sub>E</sub> =6A, di/dt = 200A/μs)		-	-	45	nC
W <sub>AVL</sub>	Avalanche Energy		0.5	_	-	mJ

<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

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# **Typical Characteristics**

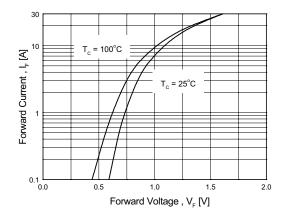


Figure 1. Typical Forward Voltage Drop vs. Forward Current

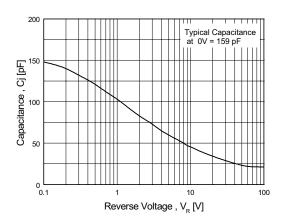


Figure 3. Typical Junction Capacitance

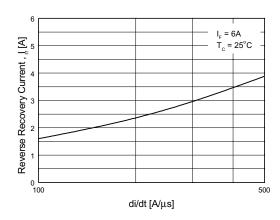


Figure 5. Typical Reverse Recovery Current vs. di/dt

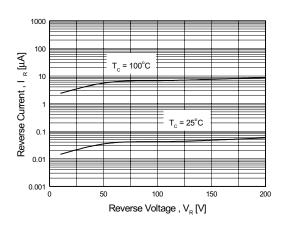


Figure 2. Typical Reverse Current vs. Reverse Voltage

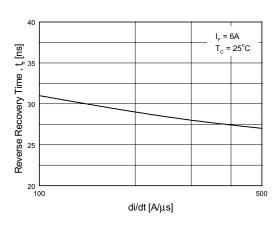


Figure 4. Typical Reverse Recovery Time vs. di/dt

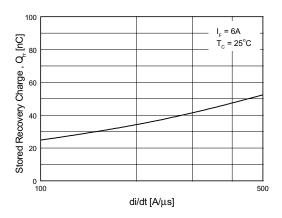
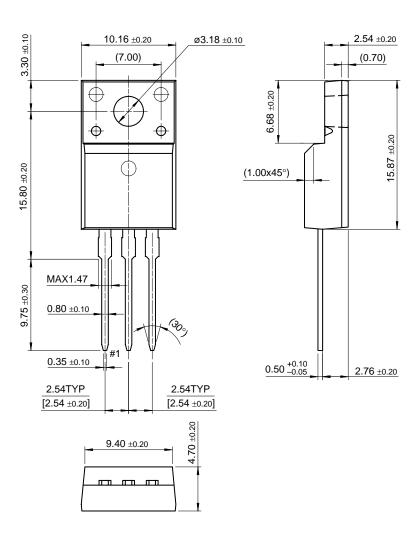


Figure 6. Typical Stored Charge vs. di/dt

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# **Package Dimensions**

# TO-220F



Dimensions in Millimeters

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